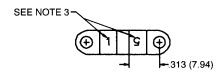
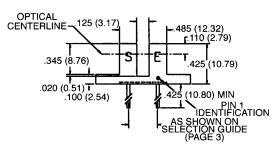
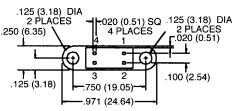


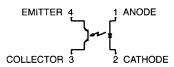
# **QVB SERIES**

# **PACKAGE DIMENSIONS**









### ST2175

### NOTES:

- 1. DIMENSIONS ARE IN INCHES (mm).
- 2. TOLERANCE IS ±.010 (.25)
- UNLESS OTHERWISE SPECIFIED.
- 3. NUMBER INDICATES APERTURE SIZE. (5 = .050", 1 = .010")

# DESCRIPTION

The QVB series of switches is designed to allow the user maximum flexibility in applications. Each switch consists of an infrared emitting diode facing an NPN phototransistor across a .125" (3.18 mm) gap. A unique housing design provides a smooth external surface to prevent dust and dirt buildup while molded internal apertures give precise positioning and also provide protection from ambient light interference.

# **FEATURES**

- Ambient light and dust protection.
- Lead spacing available at .220", .300", or .320".
- .050" and .010" aperatures available.



ABSOLUTE MAXIMUM R	ATINGS (T <sub>A</sub> = 25°C Unless Otherwise Specified)
Storage Temperature	
Lead Temperature (Iron)	
Reverse Voltage	
Emitter-Collector Voltage	

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS	
INPUT DIODE Forward voltage	V <sub>F</sub>	_		1.70	٧	I <sub>F</sub> = 20 mA	
Reverse Leakage Current	I <sub>n</sub>	_		100	μΑ	V <sub>R</sub> = 2.0 V	
OUTPUT TRANSISTOR Emitter-Collector Breakdown	BV₅∞	5			V	$I_E = 100 \ \mu A, Ee = 0$	
Collector-Emitter Breakdown	BV <sub>CEO</sub>	30		_	٧	$I_c = 1.0 \text{ mA}, Ee = 0$	
Collector-Emitter Leakage	I <sub>CEO</sub>			100	nA	V <sub>CE</sub> = 10.0 V, Ee = 0	
COUPLED On-State Collector Current	I <sub>C(ON)</sub>	See selection guide page 3.		mA	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$		
Saturation Voltage	V <sub>CE(SAT)</sub>	_		0.40	٧	I <sub>F</sub> = 20 mA, I <sub>C</sub> = 0.1 mA	

# NOTES

- Derate power dissipation linearly 1.67 mW/°C above 25°C.
   RMA flux is recommended.
   Methanol or Isopropanol alcohols are recommended as cleaning agents.
   Soldering iron tip 1/16" (1.6 mm) from housing.



PART NUMBER	LEAD SPACING	APER	TURES	I <sub>C(ON)</sub>	
		LED	SENSOR	MIN	MAX
QVB11123	.220"	0.050"	0.010"	0.20	_
QVB11124	.220"	0.050"	0.010"	0.50	
QVB11223	.300"	0.050"	0.010"	0.20	_
QVB11224	.300"	0.050"	0.010"	0.50	_
QVB11323	.320″	0.050"	0.010"	0.20	
QVB11324	.320"	0.050"	0.010"	0.50	_
QVB11133	.220"	0.050"	0.050"	0.50	_
QVB11134	.220"	0.050"	0.050"	1.00	_
QVB11233	.300″	0.050"	0.050"	0.50	_
QVB11234	.300"	0.050"	0.050"	1.00	_
QVB11333	.320"	0.050"	0.050"	0.50	
QVB11334	.320"	0.050"	0.050"	1.00	_
QVB21113	.220"	0.010"	0.010"	0.10	_
QVB21114	.220"	0.010"	0.010"	0.20	_
QVB21213	.300″	0.010"	0.010"	0.10	
QVB21214	.300"	0.010"	0.010"	0.20	<del>-</del>
QVB21313	.320"	0.010"	0.010"	0.10	_
QVB21314	.320"	0.010"	0.010"	0.20	_



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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.